

# SMALL SIGNAL PNP TRANSISTOR

## **PRELIMINARY DATA**

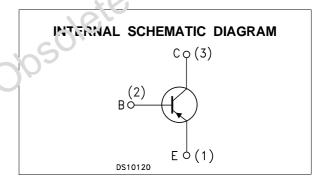
Туре	Marking		
BC857B	3F		

- SILICON EPITAXIAL PLANAR PNP TRANSISTOR
- MINIATURE SOT-23 PLASTIC PACKAGE FOR SURFACE MOUNTING CIRCUITS
- TAPE AND REEL PACKING
- THE NPN COMPLEMENTARY TYPE IS BC847B

## **APPLICATIONS**

- WELL SUITABLE FOR PORTABLE EQUIPMENT
- SMALL LOAD SWITCH TRANSISTOR WITH HIGH GAIN AND LOW SATURATION VOLTAGE





# ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
Усво	Collector-Base Voltage (I <sub>E</sub> = 0)	-50	٧
Vceo	Collector-Emitter Voltage (I <sub>B</sub> = 0)	-45	٧
$V_{EBO}$	Emitter-Base Voltage (I <sub>C</sub> = 0)	-5	V
Ic	Collector Current	-100	mΑ
I <sub>CM</sub>	Collector Peak Current	-200	mA
P <sub>tot</sub>	Total Dissipation at T <sub>C</sub> = 25 °C	250	mW
T <sub>stg</sub>	Storage Temperature	-65 to 150	О°
Tj	Max. Operating Junction Temperature	150	°C

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## THERMAL DATA

R <sub>thj-amb</sub> • Thermal Resistance Junction-Ambient	Max	500	°C/W
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<sup>•</sup> Device mounted on a PCB area of 1 cm<sup>2</sup>.

# **ELECTRICAL CHARACTERISTICS** (T<sub>case</sub> = 25 °C unless otherwise specified)

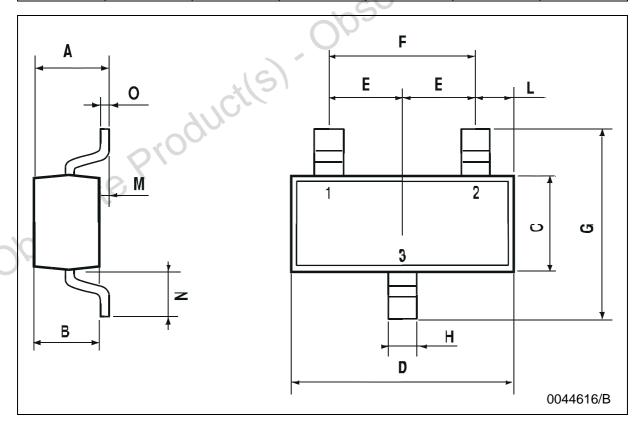
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Uni
I <sub>CBO</sub>	Collector Cut-off Current (I <sub>E</sub> = 0)	V <sub>CB</sub> = -30 V V <sub>CB</sub> = -30 V T <sub>C</sub> = 150 °C		-1	-15 -5	nA μA
I <sub>EBO</sub>	Emitter Cut-off Current (Ic = 0)	V <sub>EB</sub> = -5 V			-100	nA
V <sub>(BR)</sub> CBO	Collector-Base Breakdown Voltage (I <sub>E</sub> = 0)	I <sub>C</sub> = -10 μA	-50			V
V <sub>(BR)CEO*</sub>	Collector-Emitter Breakdown Voltage (I <sub>B</sub> = 0)	I <sub>C</sub> = -2 mA	-45			٧
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage (Ic = 0)	ΙΕ = -10 μΑ	-5		Cil	V
V <sub>CE(sat)*</sub>	Collector-Emitter Saturation Voltage	$I_{C} = -10 \text{ mA}$ $I_{B} = -0.5 \text{ mA}$ $I_{C} = -100 \text{ mA}$ $I_{B} = -5 \text{ mA}$	05	-0.07 -0.25	-0.3 -0.65	V V
VBE(sat)*	Base-Emitter Saturation Voltage	$I_{C} = -10 \text{ mA}$ $I_{B} = -0.5 \text{ mA}$ $I_{C} = -100 \text{ mA}$ $I_{B} = -5 \text{ mA}$	2	-0.7 -0.85		V V
V <sub>BE(on)</sub> *	Base-Emitter On Voltage	$I_{C} = -2 \text{ mA}$ $V_{CE} = -5 \text{ V}$ $I_{C} = -10 \text{ mA}$ $V_{CE} = -5 \text{ V}$	-0.6	-0.65	-0.75 -0.82	V
h <sub>FE</sub>	DC Current Gain	I <sub>C</sub> = -2 mA V <sub>CE</sub> = -5 V	220		475	
f <sub>T</sub>	Transition Frequency	$I_C = -10 \text{ mA } V_{CE} = -5 \text{ V } f = 100 \text{MHz}$	100			МН
ССВО	Collector-Base Capacitance	$I_E = 0$ $V_{CB} = -10 \text{ V}$ $f = 1 \text{ MHz}$		4.5		pF
NF	Noise Figure	$V_{CE}$ = -5 $V$ $I_{C}$ = -0.2 mA $f$ = 1KHz $\Delta f$ = 200 Hz $R_{G}$ = 2 $K\Omega$		2	10	dE
r uiseu. Pui:	se duration = 300 μs, duty cycle ≤	Z /0				

<sup>\*</sup> Pulsed: Pulse duration = 300 μs, duty cycle ≤ 2 %

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# **SOT-23 MECHANICAL DATA**

DIM.	mm		mils			
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
А	0.85		1.1	33.4		43.3
В	0.65		0.95	25.6		37.4
С	1.20		1.4	47.2		55.1
D	2.80		3	110.2		118
Е	0.95		1.05	37.4		41.3
F	1.9		2.05	74.8		80.7
G	2.1		2.5	82.6		98.4
Н	0.38		0.48	14.9		18.8
L	0.3		0.6	11.8	100/0	23.6
М	0		0.1	0	210	3.9
N	0.3		0.65	11.8		25.6
0	0.09		0.17	3.5		6.7



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